

### Features

- High isolation 3750 VRMS
- CTR : Min 1000%
- High B<sub>VCEO</sub> = 350V
- Operating temperature range 55 °C to 100 °C
- Green Package
- Regulatory Approvals
  - UL UL1577 (E364000)
  - VDE EN60747-5-5(VDE0884-5)
  - CQC GB4943.1, GB8898
  - IEC60065, IEC60950

### Description

The CT452 consists of a high power photodarlington transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead Mini-Flat package.

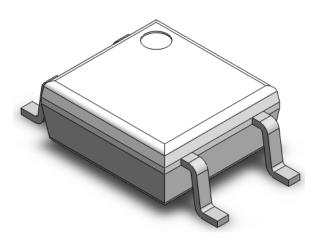
**CT452** 

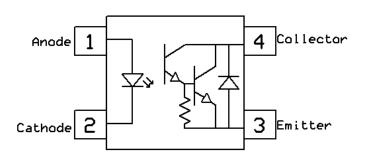
### Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

**Schematic** 

### **Package Outline**





Note: Different lead forming options available. See package

dimension.



# CT452 DC Input 4-Pin Mini-Flat High BV<sub>CEO</sub> Photo Darlington Optocoupler

## Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	3750	VRMS	
Topr	Operating temperature	-55 ~ +100	0°C	
Тstg	Storage temperature	-55 ~ +125	0°C	
Tsol	Soldering temperature	260	0C	
Ртот	Total power dissipation	170	mW	
Emitter		·	·	
IF	Forward current	60	mA	
F(TRANS)	Peak transient current (≤1µs P.W,300pps)	1	A	
VR	Reverse voltage	6	V	
Pc	Power dissipation	150	mW	
Detector	-	·	·	
PD	Power dissipation	150	mW	
B <sub>VCEO</sub>	Collector-Emitter Breakdown Voltage	350	V	
BVECO	Emitter-Collector Breakdown Voltage	0.1	V	
lc	Collector Current	150	mA	



## **Electrical Characteristics**

T<sub>A</sub> = 25°C (unless otherwise specified)

#### **Emitter Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I⊧=10mA		1.24	1.4	V	
I <sub>R</sub>	Reverse Current	$V_R = 5V$	-	-	5	μA	
CIN	Input Capacitance	f= 1MHz	-	15	-	pF	

### **Detector Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
B <sub>VCEO</sub>	Collector-Emitter Breakdown	I <sub>C</sub> = 100μA	350	-	-	V	
B <sub>VECO</sub>	Emitter-Collector Breakdown	I <sub>E</sub> = 100μA	0.1	-	-	V	
ICEO	Collector-Emitter Dark Current	V <sub>CE</sub> = 200V, I <sub>F</sub> =0mA	-	-	100	nA	

### **Transfer Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
CTR	Current Transfer Ratio	IF= 1mA, VCE= 2V	1000		15000	%	
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage	I <sub>F</sub> = 20mA, I <sub>C</sub> = 100mA	-	-	1.2	V	
Rio	Isolation Resistance	VIO= 500VDC	5x10 <sup>10</sup>			Ω	
Сю	Isolation Capacitance	f= 1MHz		0.6		pF	

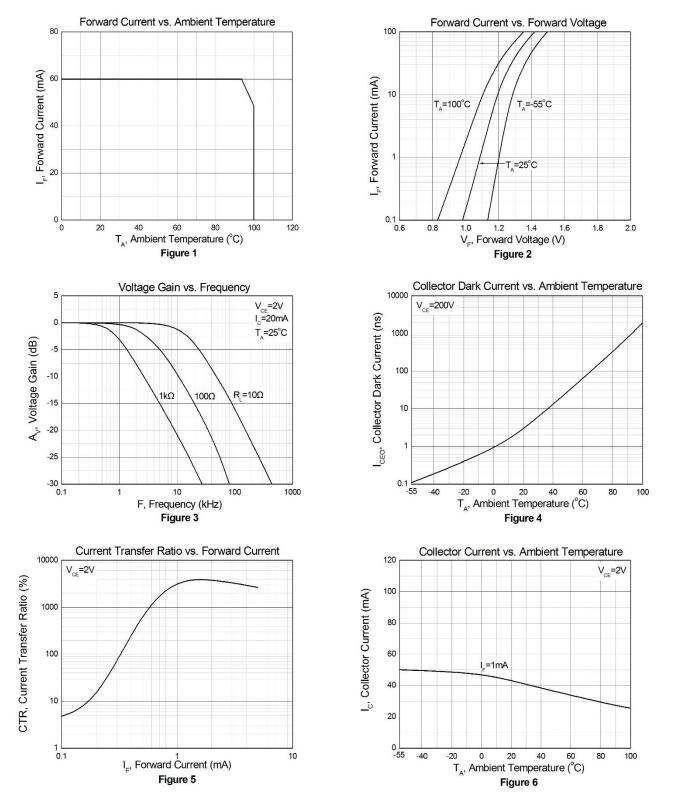
#### **Switching Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time	1 - 2mA $1/2 - 2/2$ B - 1000	-	-	250		
t <sub>f</sub>	Fall Time	I <sub>C</sub> =2mA, V <sub>CE</sub> = 2V, R <sub>L</sub> = 100Ω	-	-	95	μs	



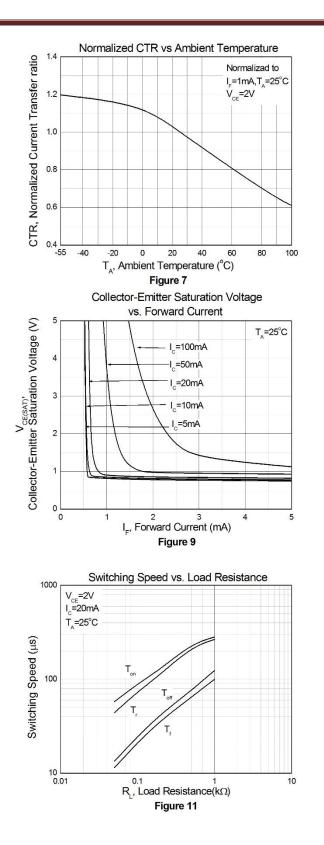
## DC Input 4-Pin Mini-Flat High BV<sub>CEO</sub> Photo Darlington Optocoupler

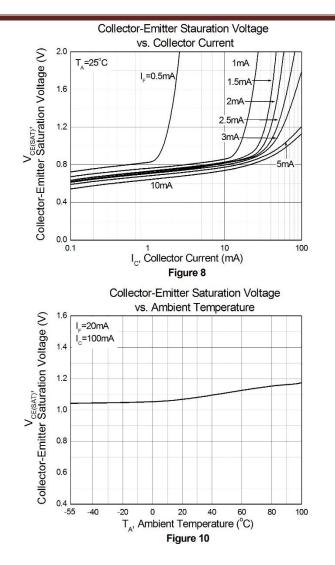
## **Typical Characteristic Curves**





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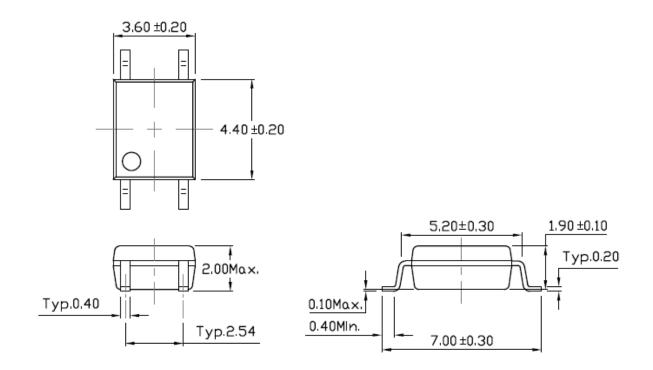




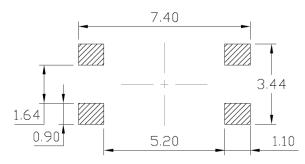


## CT452 DC Input 4-Pin Mini-Flat High BV<sub>CEO</sub> Photo Darlington Optocoupler

### Package Dimension Dimensions in mm unless otherwise stated



Recommended Solder Mask Dimensions in mm unless otherwise stated





**CT452** 

## **Marking Information**



### Note:

- CT : Denotes "CT Micro"
- 452 : Product Number
- V : VDE Option
- Y : Fiscal Year
- WW : Work Week
- K : Manufacturing Code

## **Ordering Information**

## CT452(V)(Z)

V = VDE option (V or None)

Z = Tape and reel option (T1, or T2)

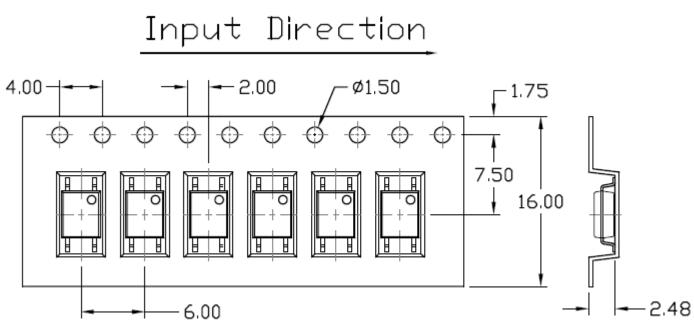
Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Taping	3000 Units/Reel
T2	T2 Surface Mount Lead Forming – With Option 2 Taping	



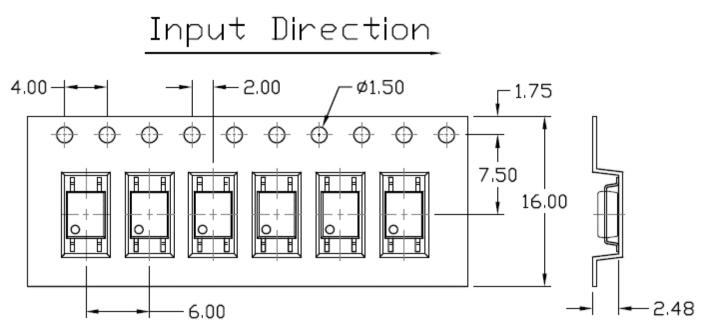
## CT452 DC Input 4-Pin Mini-Flat High BV<sub>CEO</sub> Photo Darlington Optocoupler

Carrier Tape Specifications Dimensions in mm unless otherwise stated

**Option T1** 



**Option T2** 

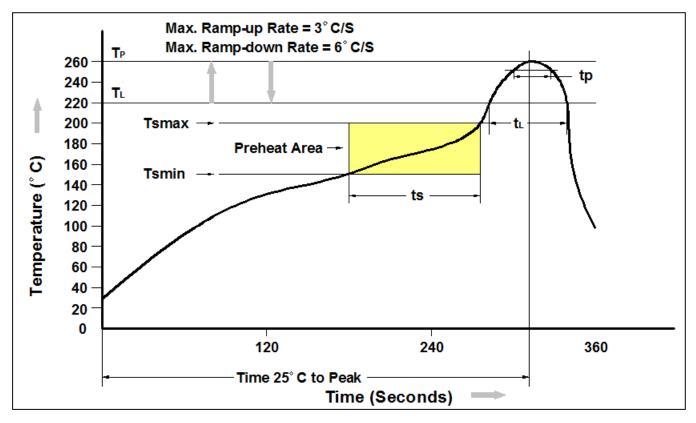




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**CT452** 

### **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile			
Temperature Min. (Tsmin)	150°C			
Temperature Max. (Tsmax)	200°C			
Time (ts) from (Tsmin to Tsmax)	60-120 seconds			
Ramp-up Rate (t∟ to t⊳)	3°C/second max.			
Liquidous Temperature (TL)	217°C			
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds			
Peak Body Package Temperature	260°C +0°C / -5°C			
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds			
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max			
Time 25°C to Peak Temperature	8 minutes max.			



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